Single 2-input OR gate
Rev. 10 — 4 September 2012

Product data sheet

1. **General description**

The 74LVC1G32 provides one 2-input OR function.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in mixed 3.3 V and 5 V applications.

Schmitt trigger action at all inputs makes the circuit tolerant of slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Features and benefits 2.

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - ♦ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
- \pm 24 mA output drive (V_{CC} = 3.0 V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



3. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|-------------|-------------------|--------|--|----------|
| | Temperature range | Name | Description | Version |
| 74LVC1G32GW | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 |
| 74LVC1G32GV | −40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads | SOT753 |
| 74LVC1G32GM | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm | SOT886 |
| 74LVC1G32GF | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body $1 \times 1 \times 0.5$ mm | SOT891 |
| 74LVC1G32GN | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm | SOT1115 |
| 74LVC1G32GS | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $1.0 \times 1.0 \times 0.35$ mm | SOT1202 |
| 74LVC1G32GX | −40 °C to +125 °C | X2SON5 | X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body $0.8\times0.8\times0.35$ mm | SOT1226 |

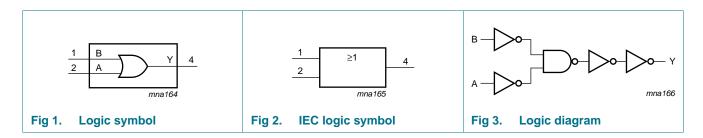
4. Marking

Table 2. Marking

| Type number | Marking code ^[1] | |
|-------------|-----------------------------|--|
| 74LVC1G32GW | VG | |
| 74LVC1G32GV | V32 | |
| 74LVC1G32GM | VG | |
| 74LVC1G32GF | VG | |
| 74LVC1G32GN | VG | |
| 74LVC1G32GS | VG | |
| 74LVC1G32GX | VG | |

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

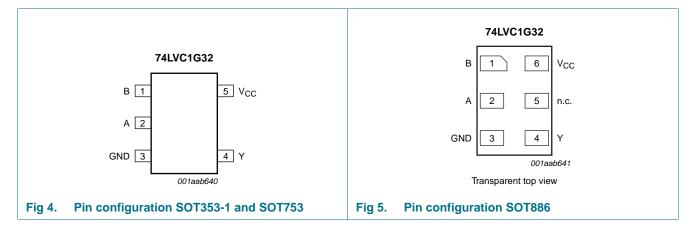
5. Functional diagram



74LVC1G32

6. Pinning information

6.1 Pinning





6.2 Pin description

Table 3. Pin description

| Symbol | Pin | | Description | |
|----------|-------------------|-------|----------------|--|
| | TSSOP5 and X2SON5 | XSON6 | | |
| В | 1 | 1 | data input | |
| Α | 2 | 2 | data input | |
| GND | 3 | 3 | ground (0 V) | |
| Υ | 4 | 4 | data output | |
| n.c. | - | 5 | not connected | |
| V_{CC} | 5 | 6 | supply voltage | |

7. Functional description

Table 4. Function table[1]

| Input | | Output |
|-------|---|--------|
| Α | В | Υ |
| L | L | L |
| L | Н | Н |
| Н | L | Н |
| Н | Н | Н |

^[1] H = HIGH voltage level; L = LOW voltage level

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| | | | | 10 | , |
|------------------|-------------------------|--|-----------------|----------------|------|
| Symbol | Parameter | Conditions | Min | Max | Unit |
| V_{CC} | supply voltage | | -0.5 | +6.5 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| V_{I} | input voltage | | <u>[1]</u> –0.5 | +6.5 | V |
| I _{OK} | output clamping current | $V_O > V_{CC}$ or $V_O < 0 V$ | - | ±50 | mA |
| V_{O} | output voltage | Active mode | [1][2] -0.5 | $V_{CC} + 0.5$ | V |
| | | Power-down mode | [1][2] -0.5 | +6.5 | V |
| I _O | output current | $V_O = 0 V \text{ to } V_{CC}$ | - | ±50 | mA |
| I _{CC} | supply current | | - | 100 | mA |
| I_{GND} | ground current | | -100 | - | mA |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ | [3] _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] When $V_{CC} = 0 \text{ V}$ (Power-down mode), the output voltage can be 5.5 V in normal operation.

^[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 and X2SON5 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-------------------------------------|---|------|-----|----------|------|
| V_{CC} | supply voltage | | 1.65 | - | 5.5 | V |
| VI | input voltage | | 0 | - | 5.5 | V |
| Vo | output voltage | Active mode | 0 | - | V_{CC} | V |
| | | V _{CC} = 0 V; Power-down mode | 0 | - | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | - | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$ | - | - | 20 | ns/V |
| | | V _{CC} = 2.7 V to 5.5 V | - | - | 10 | ns/V |

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 | °C to + | 85 °C | -40 °C t | o +125 °C | Unit |
|-----------------|----------------|--|-----------------------|---------|----------------------|-----------------------|----------------------|------|
| | | | Min | Typ[1] | Max | Min | Max | |
| V _{IH} | HIGH-level | V _{CC} = 1.65 V to 1.95 V | $0.65 \times V_C$ | - | - | $0.65 \times V_{C}$ | - | V |
| | input voltage | | С | | | С | | |
| | | V_{CC} = 2.3 V to 2.7 V | 1.7 | - | - | 1.7 | - | V |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | 2.0 | - | - | 2.0 | - | V |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | $0.7 \times V_{CC}$ | - | - | $0.7 \times V_{CC}$ | - | V |
| V_{IL} | LOW-level | V _{CC} = 1.65 V to 1.95 V | - | - | $0.35 \times V_{CC}$ | - | $0.35 \times V_{CC}$ | V |
| | input voltage | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | - | - | 0.7 | - | 0.7 | V |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | - | 0.8 | - | 0.8 | V |
| 011 | | V _{CC} = 4.5 V to 5.5 V | - | - | $0.3 \times V_{CC}$ | - | $0.3 \times V_{CC}$ | V |
| V _{OH} | HIGH-level | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | output voltage | $I_{O} = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$ | V _{CC} – 0.1 | - | - | V _{CC} - 0.1 | - | V |
| | | $I_{O} = -4 \text{ mA}$; $V_{CC} = 1.65 \text{ V}$ | 1.2 | - | - | 0.95 | - | V |
| | | $I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.9 | - | - | 1.7 | - | V |
| | | $I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$ | 2.2 | - | - | 1.9 | - | V |
| | | $I_O = -24$ mA; $V_{CC} = 3.0$ V | 2.3 | - | - | 2.0 | - | V |
| | | $I_{O} = -32 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | 3.8 | - | - | 3.4 | - | V |
| V _{OL} | LOW-level | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | output voltage | $I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$ | - | - | 0.10 | - | 0.10 | V |
| | | $I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | - | - | 0.45 | - | 0.70 | V |
| | | $I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.30 | - | 0.45 | V |
| | | $I_{O} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$ | - | - | 0.40 | - | 0.60 | V |
| | | $I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.55 | - | 0.80 | V |
| | | $I_O = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | - | - | 0.55 | - | 0.80 | V |

NXP Semiconductors 74LVC1G32

Single 2-input OR gate

 Table 7.
 Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | -40 | °C to +85 | 5 °C | –40 °C to | +125 °C | Unit |
|------------------|---------------------------------|---|-----|-----------|------|-----------|---------|------|
| | | · | Min | Typ[1] | Max | Min | Max | |
| l _l | input leakage current | $V_1 = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to 5.5 V}$ | - | ±0.1 | ±5 | - | ±100 | μΑ |
| I _{OFF} | power-off leakage current | $V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$ | - | ±0.1 | ±10 | - | ±200 | μА |
| I _{CC} | supply current | $V_I = 5.5 \text{ V or GND}; I_O = 0 \text{ A};$ $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$ | - | 0.1 | 10 | - | 200 | μА |
| ΔI_{CC} | additional supply current | per pin; $V_{CC} = 2.3 \text{ V to } 5.5 \text{ V};$ $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}$ | - | 5 | 500 | - | 5000 | μА |
| Cı | input capacitance | V_{CC} = 3.3 V; V_I = GND to V_{CC} | - | 5 | - | - | - | pF |

^[1] All typical values are measured at $V_{CC} = 3.3 \text{ V}$ and $T_{amb} = 25 \,^{\circ}\text{C}$.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for load circuit see Figure 9.

| Symbol | Parameter | Conditions | -40 | °C to +8 | 5 °C | -40 °C to | o +125 °C | Unit |
|----------|-------------------------------|--|-----|----------|------|-----------|-----------|------|
| | | | Min | Typ[1] | Max | Min | Max | |
| t_{pd} | propagation delay | A, B to Y; see Figure 8 | , | • | , | | | |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 1.0 | 3.1 | 8.0 | 1.0 | 10.5 | ns |
| | | V _{CC} = 2.3 V to 2.7 V | 0.5 | 2.1 | 5.5 | 0.5 | 7.0 | ns |
| | | V _{CC} = 2.7 V | 0.5 | 2.5 | 5.5 | 0.5 | 7.0 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 0.5 | 2.1 | 4.5 | 0.5 | 6.0 | ns |
| | | $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$ | 0.5 | 1.7 | 4.0 | 0.5 | 5.5 | ns |
| C_{PD} | power dissipation capacitance | $V_I = GND \text{ to } V_{CC}; V_{CC} = 3.3 \text{ V}$ [3] | - | 16 | - | - | - | pF |

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

 $P_D = (C_{PD} \times V_{CC}^2 \times f_i \times N) + (C_L \times V_{CC}^2 \times f_o)$ where:

 V_{CC} = supply voltage in V,

f_i = input frequency in MHz,

N = number of inputs switching,

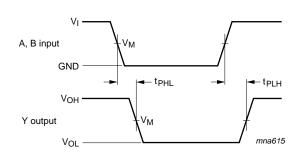
 C_L = output load capacitance in pF,

 f_o = output frequency in MHz.

^[2] t_{pd} is the same as t_{PLH} and t_{PHL} .

^[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

12. AC waveforms



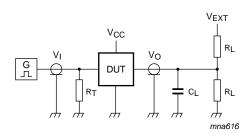
Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 8. The input A, B to output Y propagation delays

Table 9. Measurement points

| Supply voltage | Input | Output |
|------------------|-----------------------|-----------------------|
| V _{CC} | V _M | V _M |
| 1.65 V to 1.95 V | 0.5 × V _{CC} | $0.5 \times V_{CC}$ |
| 2.3 V to 2.7 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ |
| 2.7 V | 1.5 V | 1.5 V |
| 3.0 V to 3.6 V | 1.5 V | 1.5 V |
| 4.5 V to 5.5 V | 0.5 × V _{CC} | 0.5 × V _{CC} |



Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance; should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 9. Test circuit for measuring switching times

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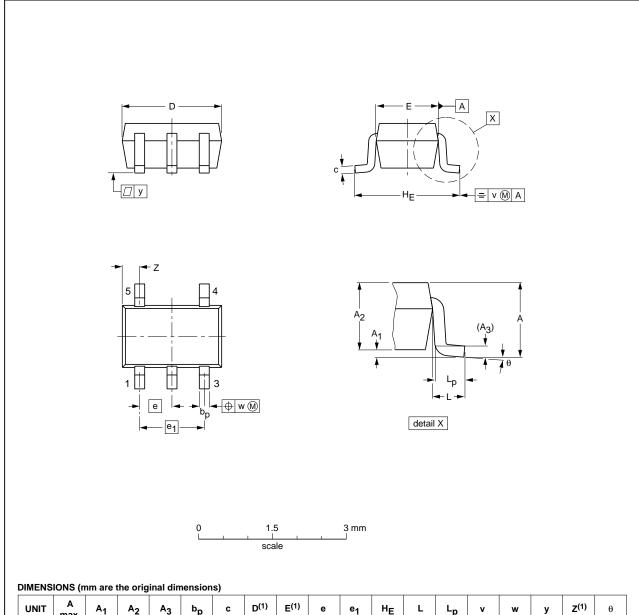
Table 10. Test data

| Supply voltage | Input | Input | | Load | | | | |
|------------------|-----------------|---------------|-------|--------------|-------------------------------------|--|--|--|
| V _{CC} | VI | $t_r = t_f$ | CL | R_L | t _{PLH} , t _{PHL} | | | |
| 1.65 V to 1.95 V | V_{CC} | \leq 2.0 ns | 30 pF | 1 kΩ | open | | | |
| 2.3 V to 2.7 V | V _{CC} | ≤ 2.0 ns | 30 pF | 500 Ω | open | | | |
| 2.7 V | 2.7 V | ≤ 2.5 ns | 50 pF | 500 Ω | open | | | |
| 3.0 V to 3.6 V | 2.7 V | ≤ 2.5 ns | 50 pF | $500~\Omega$ | open | | | |
| 4.5 V to 5.5 V | V _{CC} | ≤ 2.5 ns | 50 pF | 500 Ω | open | | | |

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



| UNIT | A max. | A ₁ | A ₂ | А3 | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | е | e ₁ | HE | L | Lp | v | w | у | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|------|--------------|--------------|------------------|------------------|------|----------------|-------------|-------|--------------|-----|-----|-----|------------------|----------|
| mm | 1.1 | 0.1 0 | 1.0 0.8 | 0.15 | 0.30 0.15 | 0.25 0.08 | 2.25 1.85 | 1.35 1.15 | 0.65 | 1.3 | 2.25 2.0 | 0.425 | 0.46 0.21 | 0.3 | 0.1 | 0.1 | 0.60 0.15 | 7° 0° |

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN | ISSUE DATE |
|--------------------|------------|--------|--------|--|------------|----------------------------------|
| | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT353-1 | | MO-203 | SC-88A | | | -00-09-01 03-02-19 |

Fig 10. Package outline SOT353-1 (TSSOP5)

74LVC1G32

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Plastic surface-mounted package; 5 leads

SOT753

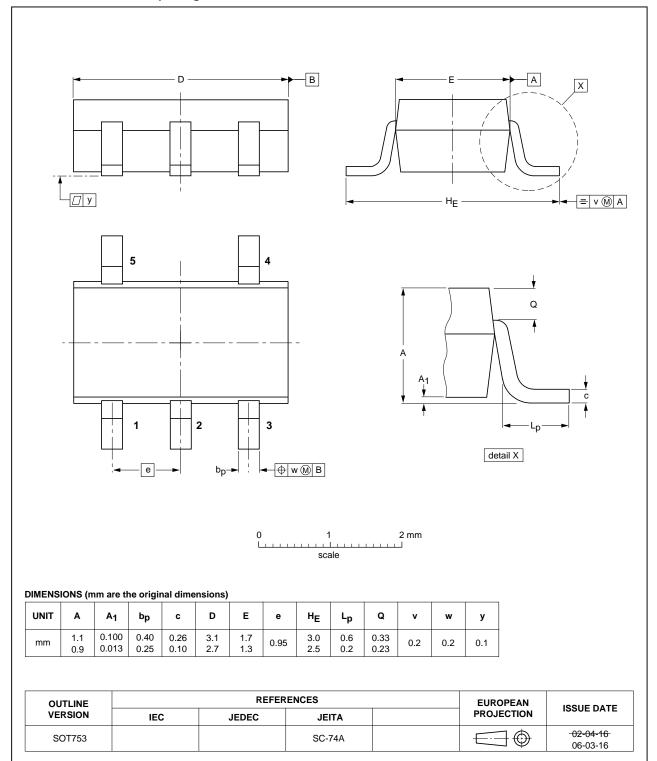


Fig 11. Package outline SOT753 (SC-74A)

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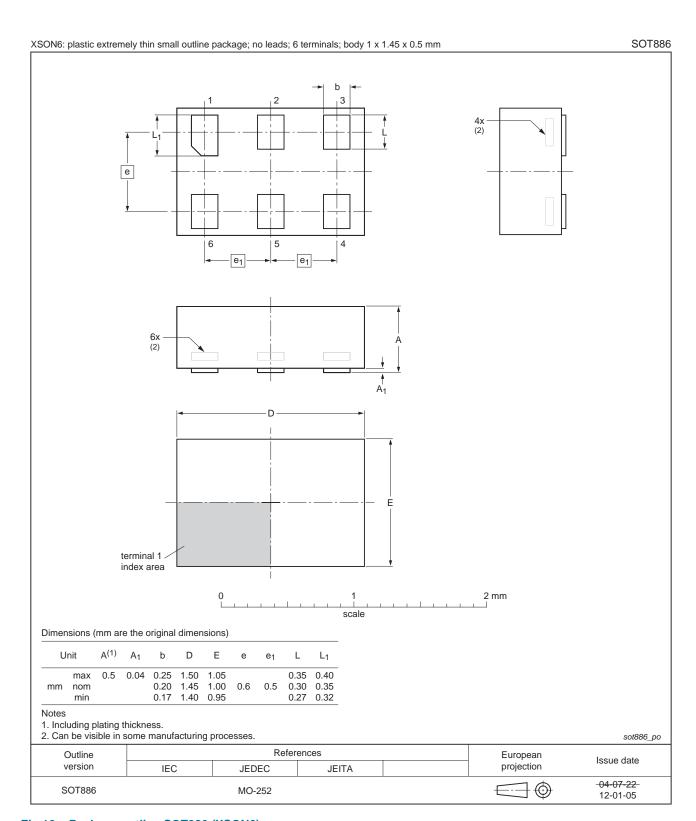


Fig 12. Package outline SOT886 (XSON6)

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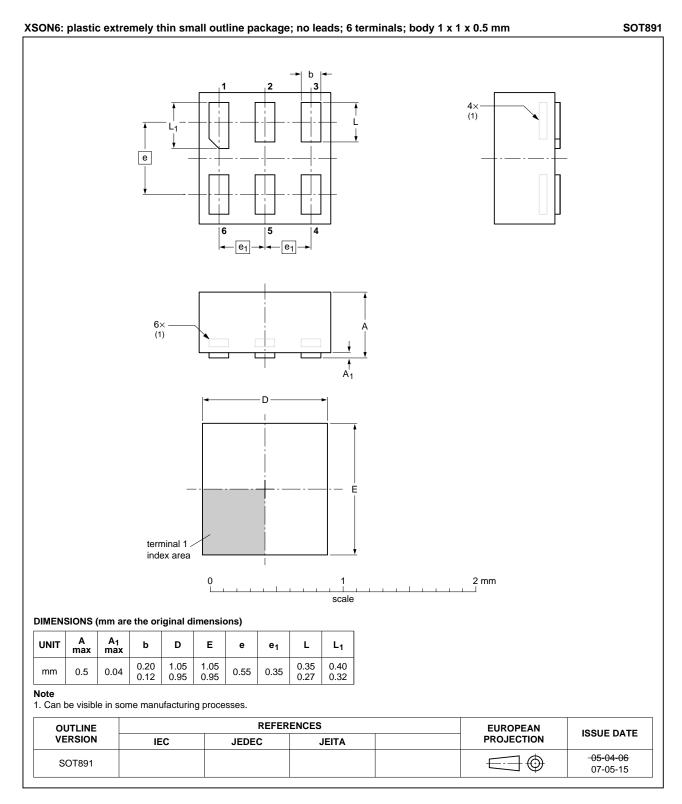


Fig 13. Package outline SOT891 (XSON6)

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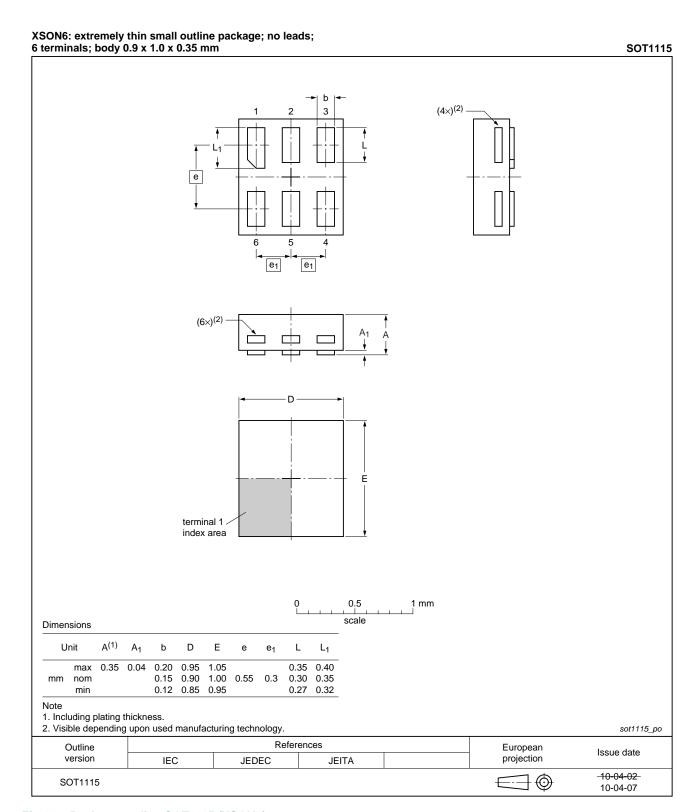


Fig 14. Package outline SOT1115 (XSON6)

74LVC1G32

Product data sheet

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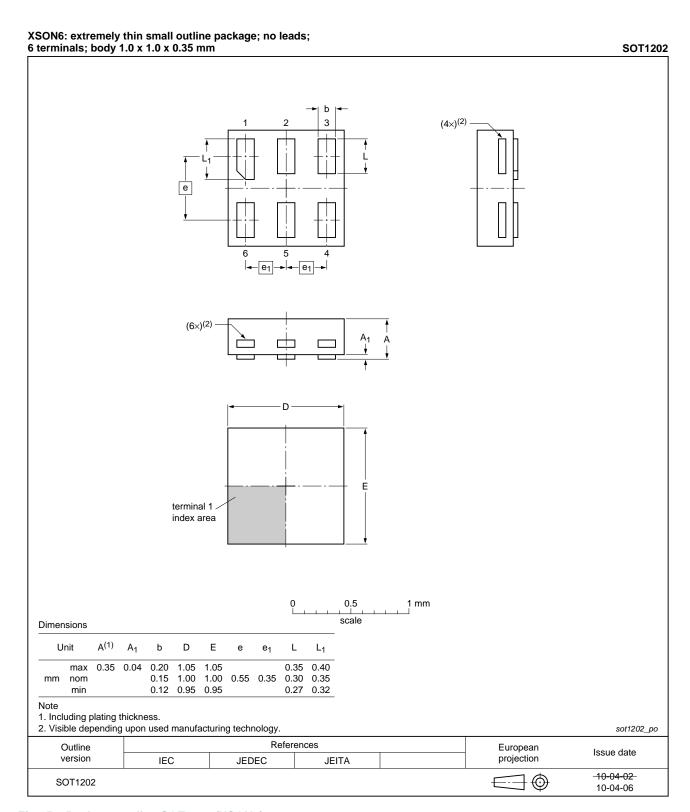


Fig 15. Package outline SOT1202 (XSON6)

Product data sheet

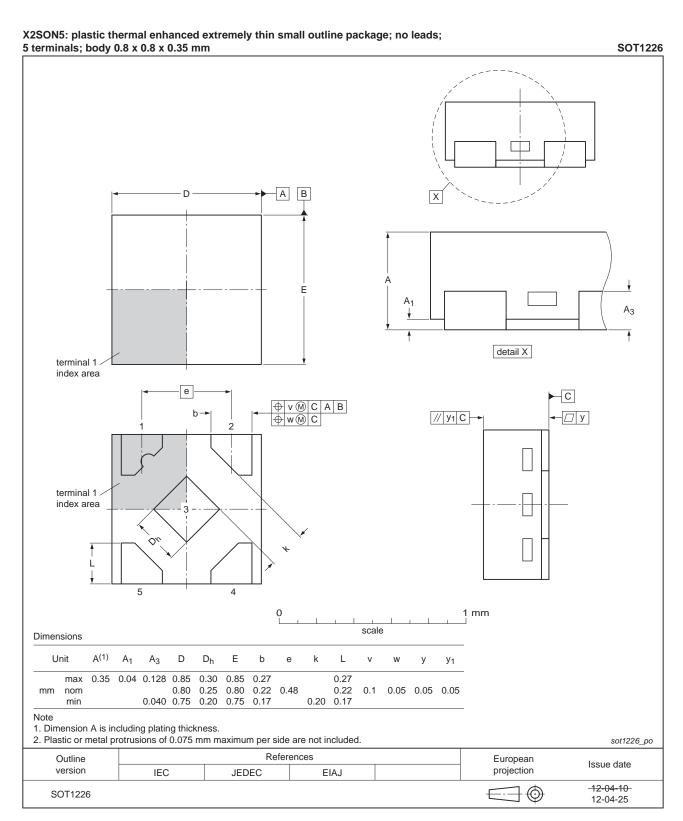


Fig 16. Package outline SOT1226 (X2SON5)

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14. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal Oxide Semiconductor |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

15. Revision history

Table 12. Revision history

| | • | | | |
|----------------|---------------------------------|-----------------------------|-----------------------|---------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| 74LVC1G32 v.10 | 20120904 | Product data sheet | - | 74LVC1G32 v.9 |
| Modifications: | Package ou | utline drawing of SOT1226 | (Figure 16) modified. | |
| 74LVC1G32 v.9 | 20120412 | Product data sheet | - | 74LVC1G32 v.8 |
| Modifications: | Added type | number 74LVC1G32GX (S | OT1226) | |
| | Package ou | ıtline drawing of SOT886 (F | figure 12) modified. | |
| 74LVC1G32 v.8 | 20111206 | Product data sheet | - | 74LVC1G32 v.7 |
| Modifications: | Legal pages | s updated. | | |
| 74LVC1G32 v.7 | 20101020 | Product data sheet | - | 74LVC1G32 v.6 |
| 74LVC1G32 v.6 | 20070802 | Product data sheet | - | 74LVC1G32 v.5 |
| 74LVC1G32 v.5 | 20060619 | Product data sheet | - | 74LVC1G32 v.4 |
| 74LVC1G32 v.4 | 20040915 | Product specification | - | 74LVC1G32 v.3 |
| 74LVC1G32 v.3 | 20021115 | Product specification | - | 74LVC1G32 v.2 |
| 74LVC1G32 v.2 | 20020521 | Product specification | - | 74LVC1G32 v.1 |
| 74LVC1G32 v.1 | 20001121 | Product specification | - | - |
| | | | | |

16. Legal information

16.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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Single 2-input OR gate

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